

Variation of Orbital Symmetry of the Localized $3d^1$ Electron of the V^{4+} Ion upon the Metal-Insulator Transition in VO_2

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The electronic structure of the vanadium dioxide VO_2 in the tetragonal R and two monoclinic M_1 and M_2 structural modifications was calculated in frames of the local-density functional (LDA) approach and the LSDA + U formalism of correction for correlation effects. Based on the results of calculation, we argue in favor of the Mott-Hubbard mechanism of the metal-insulator transition. It is shown that the transition is accompanied by the change of the orbital in which the $3d^1$ electron of the V^{4+} ion is localized. The symmetry of the filled orbital is determined by the local oxygen environment of the vanadium atoms in each structural phase. Depending on the dispersion of the band that corresponds to the orbital occupied, the investigated compound can be either a metal or an insulator.

The metal-insulator transition in VO_2 is observed at a temperature of 340 K and is accompanied by a structural transition from the nonmagnetic high-temperature tetragonal rutile phase R to the nonmagnetic monoclinic M_1 phase. The rutile phase contains chains of equidistant vanadium atoms along the $[001]$ direction. The unit cell of the M_1 phase doubles as compared to rutile, all vanadium atoms slightly deviate from the $[001]_R$ direction, forming zigzags and become nonequidistant, forming pairs.

A noncontradictory theoretical description of the metal-insulator transition in vanadium dioxide is still lacking. The origin of the nonmetallic state is explained now from two viewpoints.

If one starts from the results of band calculations in the local-density approximation (LDA), then the M_1 phase can be considered as a usual Peierls band insulator [1, 2]. From the other viewpoint, it is impossible to ignore electron correlations in the d shell of vanadium and they cannot be considered on the average, as is done in band calculations. A quarter of century ago, one more insulating phase (M_2) with local magnetic moments at some vanadium atoms was discovered. The M_2 phase originates upon slight doping of VO_2 with chromium ($\gtrsim 0.1$ at. %) [3] or upon application of a small stress along the $[110]_R$ axis [4]. In the M_2 phase, in one chain, vanadium atoms form pairs along the $[110]_R$ direction, as in the M_1 phase (but without deviation from the $[110]_R$ direction), while in the neighboring chain the atoms of vanadium again become equidistant, as in the R phase, but the zigzag configuration is preserved, as in the M_1 phase [28]. Because of the existence of a chain of equidistant V^{4+} ions, the band-theoretical description of the insulating state of the M_2 phase becomes impossible: these chains are magnetic (Mott-Hubbard) insulators. Therefore, theoretical models were developed in which the M_1 and M_2 phases were considered as the Mott-Hubbard insulators, excluding the interatomic Hubbard correlations in the R phase [6]. At the same time, arguments and experimental evidences indicating that all structural modifications of VO_2 must be considered as Mott-Hubbard

rather than as band insulators appeared in the literature [4, 5, 7, 8, 9, 10, 11].

Discussion of the nature of the insulating state in VO_2 continues with allowance for new experimental and theoretical data on the electronic structure of the R and M_1 phases. From comparison of the results of spectroscopic measurements and band calculations, it was concluded in [12] that the electronic structure of VO_2 is well described within the local-density approximation without an account of any correlation effects. Experimental measurements of the temperature dependence of the velocity of surface acoustic waves in the VO_2 single crystal near the metal-insulator transition permitted Maurer *et al.* [13] to conclude that it is unlikely that the driving force of the metal-insulator transition are electron correlations. Measurements of the delay time in the VO_2 metal/oxide/metal structures and the investigation of the influence of the injection of carriers on switching and metal-insulator transition in planar switching devices [14] also confirm exclusively the Mott-Hubbard mechanism of transition in VO_2 . It is known that the usual band calculations indicate only a tendency for the formation of an energy gap in the M_1 phase of VO_2 [2] and give a resulting metallic spectrum in contrast to the experiment. An attempt to resolve this contradiction within the band approach was made. Thus, the introduction of the electron-phonon interaction into the combination of the three-dimensional periodic-shell model and the $X\alpha$ cluster method of discrete variation resulted in the appearance of a gap in the band spectrum [15]. The introduction of the correction for self-energy within the model GW scheme also satisfactorily reproduces the properties of the non metallic M_1 phase of VO_2 observed experimentally [16]. Note that no theoretical calculations of the electronic structure of the insulating M_2 phase are available at present.

In this work, we tried to analyze in detail the electronic structure of the R , M_1 and M_2 phases of VO_2 (for the first time in the case of the M_2 phase), in each case paying attention to the orbital that is filled by the sole electron of the V^{4+} ion. With this aim in mind, we used the first-

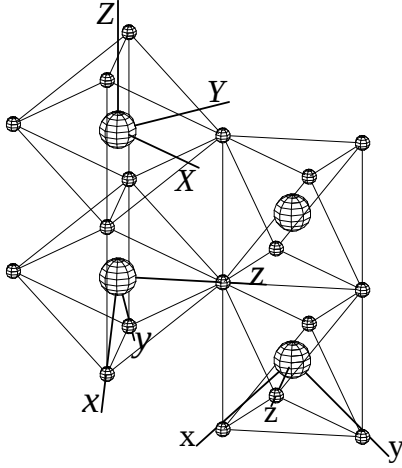


FIG. 1: The crystal structure of the R phase of VO_2 . Large spheres are the vanadium atoms, small spheres are the oxygen atoms. The axes of the crystallographic coordinate system are labeled by capital letters. The axes of the local systems of coordinates for the corner and body-center vanadium atoms are labeled by small letters.

principles linearized MT-orbital method of calculation in the tight-binding approximation (TB LMTO) [17, 18]. The nonmagnetic calculations were carried out within the conventional formalism of the local-density functional (LDA). In magnetic calculations, the electron correlations were taken into account within the LSDA+U approach [19, 20]. We used the experimentally determined values of the lattice parameters available in the literature (from [21] for the R phase, from [22] for the M_1 phase, and from [3] for the M_2 phase). In calculations, the radii of the atomic spheres of V and O were chosen to be equal with a 16% overlap; empty spheres were introduced to fill the volumes of the atomic spheres to the volume of the unit cell; the basic functions were $4s$, $4p$, and $3d$ for vanadium, $3s$, $2p$, and $3d$ for oxygen, and $1s$, $2p$, and $3d$ for the empty spheres. Within the LSDA formalism, we calculated the Coulomb U and exchange J interactions in the d shell of vanadium. The value of U was calculated with allowance for screening of the t_{2g} electrons by the e_g electrons [23]. The values $U = 3.8$ eV and $J = 1.0$ eV obtained were used unchanged in calculations of the electronic structure of all phases [29]. Thus, our calculations do not contain adjustable parameters and, in this sense, are the first-principles.

The unit cell of the high-temperature R phase of VO_2 (space group $P4_2/mnm$) contains two formula units. The vanadium atoms form a body-centered tetragonal lattice and are surrounded by slightly deformed oxygen octahedra. In such octahedra, the V–O distances in the direction normal to the tetragonal c axis are slightly greater than the V–O distances in the plane parallel to the c axis (Fig. 1 and table). In the same plane, the O–V–O angles are 84.2° and 95.8° , while the other O–V–O angles are

equal to 90° . The octahedra surrounding the vanadium atoms in the vertices and in the center of the unit cell are rotated by 90° about the c axis. In what follows, we will present the results for each vanadium atom in the local coordinate system, in which the z axis is directed toward one of the most remote oxygen atoms (apical atom) in the octahedra. The direction of the chain of vanadium atoms along the c axis is the bisector of the angle which is made by the x and y axes of the local coordinate system (see Fig. 1). The Euler angles used for passage from the crystallographic coordinate system to the local one for the vanadium atom at the position $(0;0;0)$ are the set $(\frac{\pi}{4}; \frac{\pi}{2}; -\frac{\pi}{4})$.

Let us clarify the terms that will be used in the interpretation of the results. By occupancy of the i th orbital, we mean the integral $N_i = \int_{-\infty}^{\varepsilon_F} n_i(\varepsilon) d\varepsilon$ where $n_i(\varepsilon)$ is the corresponding partial density of states, and ε_F is the Fermi energy. By the center of gravity of the i th band, we mean the ratio $\varepsilon_i^{cg} \equiv \langle \varepsilon_i \rangle = \int_{\varepsilon_1}^{\varepsilon_2} \varepsilon n_i(\varepsilon) d\varepsilon / \int_{\varepsilon_1}^{\varepsilon_2} n_i(\varepsilon) d\varepsilon$, where ε_1 and ε_2 are the boundaries of the energy interval under consideration. By the dispersion of the i th band, the expression $\sigma_i = \sqrt{\langle \varepsilon_i^2 \rangle - \langle \varepsilon_i \rangle^2}$ is meant. Because of the distortion of the oxygen octahedra, the t_{2g} orbitals of the vanadium atom become nondegenerate. The xy , $yz - zx$, and $yz + zx$ wave functions, where x , y , and z represent the basis of the local system of coordinates, will be the natural basis for the t_{2g} orbitals.

The results of the nonmagnetic LDA calculation are shown in Fig. 2. Our LDA calculations show: (1) owing to the elongation of the oxygen octahedra along the local z axis, the $yz - zx$ orbital is most populated; (2) the center of gravity of the $yz - zx$ band lies most deeply in the energy range from -8 to $+6$ eV; (3) in the energy interval from -1.5 to $+1.8$ eV, the dispersion of the $yz - zx$ band is approximately one and half times greater than that for the xy and $yz + zx$ bands.

We also carried out LSDA+U calculations for the R phase of VO_2 for the ferromagnetic and antiferromagnetic types of ordering of magnetic moments of vanadium ions in the chains located along the tetragonal c axis. In the first case, the half-metallic ferromagnetic state is ob-

TABLE I: The V–O distances ($\text{\AA}$) for the R and M_1 phases and the average distances for the M_2 phase of VO_2 . The "apical" and "in-plane" oxygen atoms are considered in the local coordinate systems: the z axis passes through the apical oxygen and the x and y axes pass through the in-plane oxygen atoms.

Oxygen atoms	R	M_1	M_2	
			in the dimerized chains	in the undimerized chains
Apical	1.93	1.91	1.87	1.93
In-plane	1.92	1.94	1.97	1.95

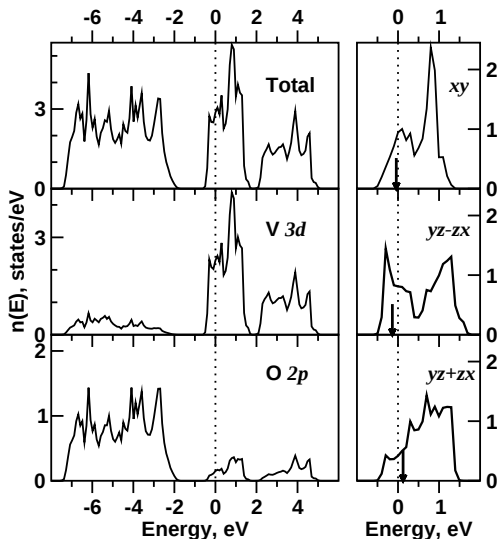


FIG. 2: The total (per formula unit) and partial (per atom) densities of states for the *R* phase of VO₂ (left column) and the *t*_{2g} orbital partial density of states for the vanadium atoms (right column). The positions of the Fermi level are shown by dotted lines. Arrows in the right column indicate the centers of gravity of the orbital partial densities of states in the energy range from -8 to +6 eV.

tained with the spin magnetic moment of the *d* shell of vanadium equal to $\mu=0.99 \mu_B$. In the second case the antiferromagnetic state was found to be insulating with an energy gap of 0.38 eV and $\mu=0.90 \mu_B$. The second solution was lower than the first one in the total energy. For both solutions the sole *d* electron of the V⁴⁺ ion was localized in the *yz* - *zx* orbital (Fig. 3). This naturally follows from the above results ((1) and (2)) of the LDA calculations: within the LSDA+U approach, the orbital that already was most populated and whose center of gravity was already the lowest among all the *t*_{2g} orbitals is occupied. The third result (the maximum dispersion of the *yz* - *zx* band) has preserved the ferromagnetic state as the metallic one even within the LSDA+U calculation and led to the appearance of the antiferromagnetic insulating state with a small energy gap[30].

The fact that the LSDA+U calculations predict the antiferromagnetic insulating state for the *R* phase of VO₂ instead of the metallic one reflects the known tendency of the LSDA+U method to overestimate the electron localization as a result of consideration of the on-site spin- and orbit-dependent Coulomb repulsion in terms of the mean-field theory. At the same time, the LSDA+U approach gives an accurate description of the orbital nature of the localized electrons[31]. Our calculations of the electron structure of VO₂ in the *R* phase predict localization of the *d* electron of the V⁴⁺ ion on the *yz* - *zx* orbital. As will be seen below, this result is a key one for the description of the metal-insulator transition in VO₂.

Analysis of the partial densities of the *t*_{2g} states of

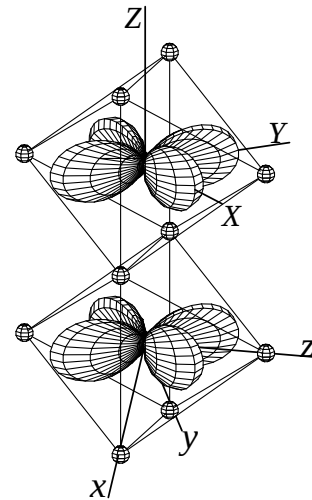


FIG. 3: Ordering of the occupied *yz* - *zx* orbitals in the chain of the vanadium atoms obtained as a result of the LSDA+U calculation for the *R* phase of VO₂. For designations, see Fig. 1. The orbitals shown represent the angular distribution of the *d* electron density of the vanadium atoms $\rho(\theta, \phi) = \sum_{m,m'} Q_{m,m'} Y_m(\theta, \phi) Y_{m'}(\theta, \phi)$, where $Q_{m,m'} = n_{m,m'}^\uparrow - n_{m,m'}^\downarrow$ is the difference between the population matrices of the *d* states of the vanadium atoms with spins up and down obtained by self-consistent calculation, and $Y_m(\theta, \phi)$ are the corresponding spherical harmonics.

vanadium, obtained in the nonmagnetic LDA calculation for the *M*₁ phase and shown in Fig. 4, indicates a different sequence of filling orbitals, as compared to the *R* phase. The *M*₁ phase (the space group *P*2₁/*c*) is characterized by a pairing of the vanadium atoms along the [0.842; 0; -0.539] vector in the crystallographic coordinate system: there are short and long vanadium-vanadium bonds. Moreover, each pair of vanadium atoms is inclined relative to this vector in the plane with the normal [0.381; 0.708; 0.595] for one chain of vanadium atoms and to the plane with the normal [0.381; -0.708; 0.595] for the neighboring chain. The difference in the oxygen surroundings of the vanadium atoms is not only in the variation of the O-V-O angles, but also in that the V-O distance to the apical oxygen atoms in the *M*₁ phase became smaller than to the in-plane oxygens (see table). We define the local system of coordinates for the *M*₁ phase in the following way: the *z* axis is perpendicular to the plane of the vanadium atoms that belong to the same chain, and the *x* and *y* axes are deflected by an angle of 45° from the direction of the chain (Fig. 5). In other words, the local system of coordinates for the *M*₁ phase is chosen similar to that for the *R* phase. Then, for the vanadium atom in the (0.259; -0.025; -0.136) position, the Euler angles for passing from the crystallographic system of coordinates to the local one will be (0.658π; -0.297π; -0.984π).

Comparing the partial densities of the *t*_{2g} states of

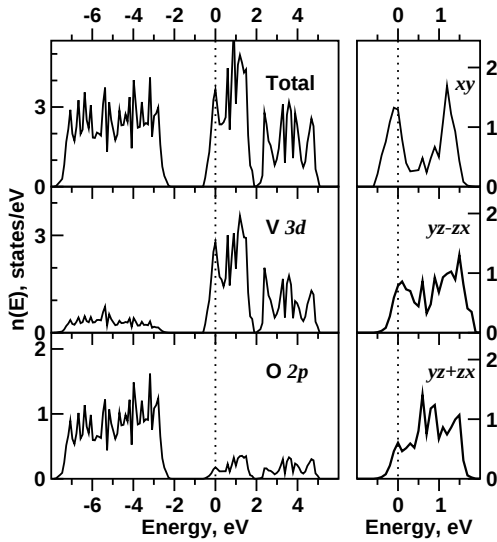


FIG. 4: The total (per formula unit) and partial (per atom) densities of states for the M_1 phase of VO_2 (left column) and the t_{2g} partial densities of states for the vanadium atoms (right column). The Fermi level is shown by dotted lines.

vanadium for the R and M_1 phases (see Figs. 2 and 4), note a substantial difference in the density of states for the xy orbital. Owing to dimerization of the vanadium atoms, the corresponding band for the M_1 phase is split into bonding and antibonding subbands and, which is more important, the filling of the xy orbital becomes maximum between the t_{2g} orbitals. The nonmagnetic LDA calculation does not reproduce the insulating nature of the energy spectrum for the M_1 phase of VO_2 . Yet, it is clear that the allowance for correlations in calculations will not change this key result, i.e., the preferential filling of the orbitals of the xy symmetry.

The conclusion concerning filling of the $3d^1$ xy states of the M_1 phase is supported by two factors. First, the distortions of the oxygen octahedra around the vanadium atom occur in such a way that the maximum V-O distances are observed in the xy plane in the local system of coordinates (see table), which, in turn, lowers the energy of the xy orbital. Second, we performed the LSDA+U calculations for the M_1 structure to determine which of the orbitals will be filled by the localized electron[32]. Note that the LSDA+U calculation predicts for the M_1 phase the antiferromagnetic ground state with a gap equal to 0.55 eV and the spin magnetic moment of the d shell of vanadium $\mu=0.81 \mu_B$ instead of the nonmagnetic insulating state with a gap of 0.2-0.7 eV observed experimentally [9, 27]. Quantum corrections, probably, could suppress the long-range magnetic order obtained in the LSDA+U calculation, and the calculated value of the gap is within the limits of the experimental one. Yet, turning to the discussion of the orbital nature of the localized d electron, one can see from Fig. 5 that the xy orbital became localized. Both factors permit us

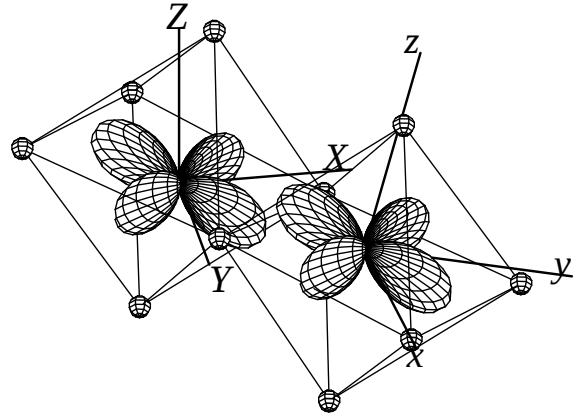


FIG. 5: Ordering of the occupied xy orbitals in the chain of vanadium atoms obtained as a result of the LDA+U calculation for the M_1 phase of VO_2 . The axes of the crystallographic system of coordinates are marked by capital letters. The axes of the local system of coordinates for the vanadium atoms are marked by small letters.

to conclude that upon transition of VO_2 from the R to the M_1 phase, along with a change in the ratio of the distances from the vanadium atom to the in-plane oxygen atom and to the apical oxygen atom, an important transformation of orbital symmetry of the localized $3d^1$ electron of the V^{4+} ion occurs, namely, from the $yz - zx$ to the xy .

We believe that the Peierls mechanism is not responsible for the formation of the insulating state of the M_1 phase. Even the LDA results show that the most filled orbitals in both cases are different: the xy orbital for the M_1 phase and the $yz - zx$ orbital for the R phase. It is known (for example, from the theoretical investigations of CrO_2 [24] which also has a crystal structure of the rutile type) that the $yz - zx$ band has substantial dispersion and is strongly hybridized with the $\text{O}2p$ states, forming the π bond with them. Therefore, it is weakly localized even in the presence of strong correlations and the energy spectrum may remain metallic in the case of the preferential filling of this band. At the same time, the xy band is narrower than the $yz - zx$ one and more sensitive to correlations. This results in localization of electrons on the xy orbital, its complete filling, and the appearance of a gap in the energy spectrum. It is what we obtained in our LSDA+U calculations. Thus, we can conclude that it is the Mott-Hubbard mechanism that is responsible for the formation of the energy gap in VO_2 . The Peierls's mechanism can be used only for explanation of the insulating state of the M_1 phase, but it is completely unacceptable for the M_2 phase, in which both dimerized and undimerized chains of vanadium atoms exist simultaneously. Taking into account which orbitals are filled by the d electron in each particular case and which are the properties of these orbitals, the Mott-Hubbard mechanism can be applied for the description of both metallic

and insulating states of all crystal phases of VO_2 .

The calculations of the electronic structure of the M_2 phase (space group $C2/m$) fully confirm our assumption about the mechanism of formation of energy bands in VO_2 . Both dimerized chains of vanadium atoms (similar to the chains in the M_1 phase) and the undimerized ones (as in the R phase) exist in the crystal structure of the M_2 phase. As in the M_1 phase, but contrary to the R phase, the V-O distances to the apical oxygen atoms in the oxygen octahedra which surround the vanadium atoms in both types of chains are smaller than to the in-plane oxygens. The Euler angles for the passage to the local system of coordinates for the vanadium atoms in the dimerized and undimerized chains (Fig. 6) are given by the sets of $(-\pi; -\frac{\pi}{4}; \frac{\pi}{4})$ and $(0; -\frac{\pi}{4}; \frac{\pi}{4})$.

The "nonmagnetic" calculations in the local-density approximation give the metallic ground state, which contradicts the experiment. Owing to a substantial distortion of the crystal structure and, correspondingly, complicated hybridization of the d states of vanadium with each other, it is impossible here to consistently separate the partial densities of the t_{2g} states in the cubic harmonics, which we had done, for example, for the R phase. The LSDA+U calculation is the sole possibility of determining which localized t_{2g} orbital will be filled.

The results of such a calculation are shown in Fig. 6. They demonstrate the occupied orbitals of vanadium that in the M_2 phase are the xy orbitals both in the dimerized and undimerized chains. According to calculations, in the case of antiferromagnetic ordering the spin magnetic moment of the d shell of vanadium that belongs to the undimerized chain is equal to $\mu = 0.89 \mu_B$ and the arising energy gap is 0.93 eV. We also calculated the exchange-correlation parameter J of the Heisenberg model for the vanadium atoms in the undimerized chain (the scheme of calculation within the LSDA+U method is described in [20]. Its value was found to be 205 K and the sign corresponds to the antiferromagnetic exchange. The value obtained is close to the result of [8] where, from an analysis of nuclear magnetic resonance experiments, it is shown that the V^{4+} ions in the undimerized chains behave as Heisenberg chains with spin $S = 1/2$ and antiferromagnetic exchange $J \approx 300$ K.

Thus, the principal difference between the rutile R phase and the monoclinic M_1 and M_2 phases is which of the localized t_{2g} orbitals is filled by the sole $3d$ electron of the V^{4+} ion: $yz - zx$ or xy . The choice of the filled orbital is determined by the local oxygen surroundings of the vanadium atoms. Since these bands have different properties relative to localization (or dispersion), the correlation effects variously influence the energy spectrum (metal or insulator) depending on which band is filled. It is correlations (the Mott-Hubbard mechanism) that are responsible for the insulating properties of the M_1 and M_2 phases of VO_2 . Correlations are also present in the metallic R phase. Owing to the localization of the d

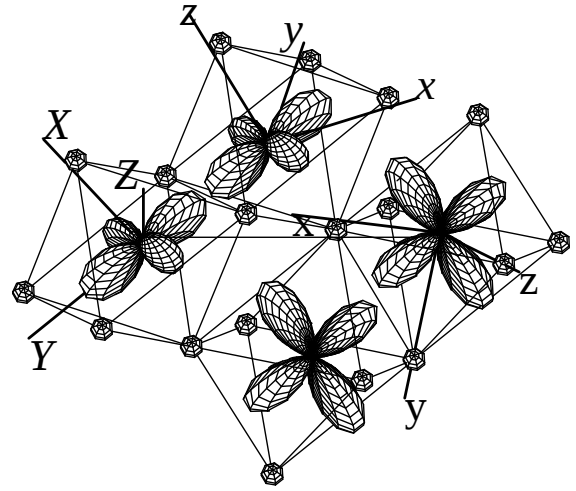


FIG. 6: Ordering of the occupied xy orbitals in the dimerized (upper left part of the figure) and the undimerized (lower right part of the figure) chains of the vanadium atoms obtained by the LSDA+U calculation for the M_2 phase of VO_2 . The axes of the crystallographic system of coordinates are marked by capital letters. The axes of the local systems of coordinates are shown by small letters.

electron in the $yz - zx$ orbital, they do not lead to the appearance of a gap in the band spectrum.

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- [28] The diagram of mutual arrangement of V atoms in the three VO_2 phases can be found, for example, in [[5], Fig. 215]. The phase diagram is shown in [[5], Fig. 217]. The triclinic T phase of VO_2 will not be considered in this work.
- [29] The existing experimental estimates of the Coulomb interaction U in VO_2 [9] give 2.1 eV for the insulating phase and 1.3 eV for the metallic phase. These values are slightly below that used in calculations $U = 3.8$ eV.
- [30] For $U \leq 3.0$ eV, the antiferromagnetic state of the R phase in the LSDA+ U calculation is metallic. See also [29].
- [31] This is shown in the series of our works devoted to the investigation of orbital filling in CrO_2 [24] $KCuF_3$ perovskites [20], $PrMnO_3$ [25], layered vanadates of the CaV_nO_{2n+1} -type [26], etc.
- [32] In calculating the M_1 and M_2 phases of VO_2 , it is incorrect to substantiate conclusions by comparing the centers of gravity of orbitals and the dispersions of the corresponding bands obtained in nonmagnetic LDA calculations in view of the lower symmetry of these phases and substantial hybridization of the states under investigation.